Notice of Allowability	Application No.	Applicant(s)
	09/944,085	KAZUTAKA ET AL.
	Examiner	Art Unit
	Leonid Shapiro	2673
The MAILING DATE of this communication appears on the cover sheet with the correspondence address All claims being allowable, PROSECUTION ON THE MERITS IS (OR REMAINS) CLOSED in this application. If not included herewith (or previously mailed), a Notice of Allowance (PTOL-85) or other appropriate communication will be mailed in due course. THIS NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGHTS. This application is subject to withdrawal from issue at the initiative of the Office or upon petition by the applicant. See 37 CFR 1.313 and MPEP 1308.		
1. This communication is responsive to 10/15/04.		
2. A The allowed claim(s) is/are 1-45.		
3. A The drawings filed on <u>04 September 2001</u> are accepted by the Examiner.		
<ul> <li>4.  Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).</li> <li>a)  All b)  Some* c) None of the:</li> <li>1.  Certified copies of the priority documents have been received.</li> <li>2.  Certified copies of the priority documents have been received in Application No</li> <li>3.  Copies of the certified copies of the priority documents have been received in this national stage application from the International Bureau (PCT Rule 17.2(a)).</li> <li>* Certified copies not received:</li> </ul>		
Applicant has THREE MONTHS FROM THE "MAILING DATE" of this communication to file a reply complying with the requirements noted below. Failure to timely comply will result in ABANDONMENT of this application.  THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		
5. A SUBSTITUTE OATH OR DECLARATION must be submitted. Note the attached EXAMINER'S AMENDMENT or NOTICE OF INFORMAL PATENT APPLICATION (PTO-152) which gives reason(s) why the oath or declaration is deficient.		
<ul> <li>6. CORRECTED DRAWINGS ( as "replacement sheets") must be submitted.</li> <li>(a) including changes required by the Notice of Draftsperson's Patent Drawing Review ( PTO-948) attached</li> <li>1) hereto or 2) to Paper No./Mail Date</li> <li>(b) including changes required by the attached Examiner's Amendment / Comment or in the Office action of Paper No./Mail Date</li> <li>Identifying indicia such as the application number (see 37 CFR 1.84(c)) should be written on the drawings in the front (not the back) of each sheet. Replacement sheet(s) should be labeled as such in the header according to 37 CFR 1.121(d).</li> <li>7. DEPOSIT OF and/or INFORMATION about the deposit of BIOLOGICAL MATERIAL must be submitted. Note the</li> </ul>		
attached Examiner's comment regarding REQUIREMENT FOR THE DEPOSIT OF BIOLOGICAL MATERIAL.		
Attachment(s)  1. Notice of References Cited (PTO-892)	5 Notice of Informal D	otent Application (DTO 452)
Notice of Neterences Cited (FTO-092)     Notice of Draftperson's Patent Drawing Review (PTO-948)	6. ☐ Interview Summary	atent Application (PTO-152) (PTO-413).
3. ☐ Information Disclosure Statements (PTO-1449 or PTO/SB/0	Paper No./Mail Dat	è ´
Paper No./Mail Date4.   Examiner's Comment Regarding Requirement for Deposit	<u> </u>	
of Biological Material	9. Other	nt of Reasons for Allowance
	. <u> </u>	

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## Allowable Subject Matter

3. Claims 1-45 are allowed.

4. The following is a statement of reasons for the indication of allowable subject matter:

Relative to independent claims 1, 5, 9, 13, 17 and 21 the major difference between the teaching of the prior art of record (Someya, Kane and Naka) and the instant invention is that the said prior art **does not teach** after each of the n+m display periods begins completing the respective display period by timing on the third TFT; wherein the organic EL element emits light when the second TFT is turned on, and does not emit light when the second TFT is turned off; wherein the first TFT comprises a crystalline semiconductor film, a gate insulating film over the crystalline semiconductor film first and second Mate electrodes formed over the crystalline semiconductor film with the gate insulating film interposed therebetween, and first and second channel forming regions in the crystalline semiconductor film below the first and second gate electrodes, respectively, and a pair of first impurity regions in the crystalline semiconductor film between the first and second channel forming regions and a third impurity.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

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Art Unit: 2673

## Telephone inquire

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Leonid Shapiro whose telephone number is 703-305-5661. The examiner can normally be reached on 8 a.m. to 5 p.m..

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Bipin Shalwala can be reached on 703-305-4938. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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12.22.04

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